

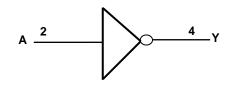
74AHC1G04

SINGLE INVERTER GATE

Pin Descriptions

Pin Name	Pin NO.	Description
NC	1	No Connection
A	2	Data Input
GND	3	Ground
Y	4	Data Output
V _{CC}	5	Supply Voltage

Logic Diagram



Function Table

Inputs	Output
А	Y
Н	L
L	Н



SINGLE INVERTER GATE

Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI<0	-20	mA
I _{OK}	Output Clamp Current ($V_O < 0$ or $V_O > V_{CC}$)	±20	mA
Ι _Ο	Continuous output current ($V_0 = 0$ to V_{CC})	±25	mA
I _{CC}	Continuous current through V _{CC}	50	mA
I _{GND}	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol	F	Parameter	Min	Мах	Unit
V _{CC}	Operating Voltage		2	5.5	V
		$V_{CC} = 2V$	1.5		
VIH	High-level Input Voltage	$V_{CC} = 3V$	2.1		V
		$V_{CC} = 5.5V$	3.85		
		$V_{CC} = 2V$		0.5	
VIL	Low-level input voltage	$V_{CC} = 3V$		0.9	V
		$V_{CC} = 5.5V$		1.65	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		$V_{CC} = 2V$		-50	uA
I _{OH}	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-4	mA
		$V_{CC} = 5V \pm 0.5V$		-8	ША
		$V_{CC} = 2V$		50	uA
I _{OL}	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4	
		$V_{CC} = 3V$		8	mA
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	ns/V
	rate	$V_{CC} = 5V \pm 0.5V$		20	115/ V
T _A	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at $V_{\mbox{\scriptsize CC}}$ or Ground.



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Electrical Characteristics

Cumber I	Parameter	Test Conditions	V		25⁰C		-40ºC t	o 85ºC	-40°C t	o 125⁰C	Unit
Symbol Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Min	Max	Unit	
		Ι _{ΟΗ} = -50μΑ	2V	1.9	2		1.9		1.9		
			3V	2.9	3		2.9		2.9		
V _{OH}	High Level		4.5V	4.4	4.5		4.4		4.4		V
-	Output Voltage	I _{OH} = -4mA	3V	2.58			2.48		2.40		
		I _{OH} = -8mA	4.5V	3.94			3.8		3.70		
			2V			0.1		0.1		0.1	
		I _{OL} = 50μΑ	3V			0.1		0.1		0.1	
V _{OL}	Low Level Output Voltage		4.5V			0.1		0.1		0.1	V
	Output voltage	$I_{OL} = 4mA$	3V			0.36		0.44		0.55	
		I _{OL} = 8mA	4.5V			0.36		0.44		0.55	
l _l	Input Current	$V_1 = 5.5 V \text{ or GND}$	0 to 5.5V			± 0.1		± 1		±2	μA
I _{CC}	Supply Current	V _I = 5.5V or GND I _O =0	5.5V			1		10		40	μA
CI	Input Capacitance	$V_I = V_{CC} - or GND$	5.5V		2.0	10		10		10	pF
0	Thermal Resistance	SOT25	(Nata 4)		195						°C/W
θ_{JA}	Junction-to- Ambient	SOT353	(Note 4)		430						C/W
θ _{JC}	Thermal Resistance	SOT25	(Note 4)		58						°C/W
olC	Junction-to- Case	SOT353	(11018 4)		155						0/00

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

Switching Characteristics

V_{CC} = 3.3 V ± 0.3 (see Figure 1)

Deremeter	From	то			25⁰C		-40⁰C t	o 85⁰C	-40°C to	o 125⁰C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	Δ	V	C _L =15pF	0.6	4.3	7.1	0.6	8.5	0.6	11.0	ns
٩d	A	ř	C _L =50pF	0.6	6.1	10.6	0.6	12.0	0.6	14.5	ns

V_{CC} = 5 V ± 0.5V (see Figure 1)

Parameter	From	то			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	Unit
Faranieler	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
+ .	٨	V	C _L =15pF	0.6	3.1	5.5	0.6	6.5	0.6	7.0	ns
٩d	A	r	C _L =50pF	0.6	4.5	7.5	0.6	8.5	0.6	9.5	ns



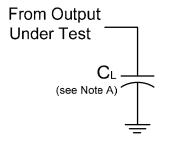
SINGLE INVERTER GATE

Operating Characteristics

T_A = 25 °C

	Parameter	Test Conditions	V _{CC} = 5V Typ.	Unit
C _{pd}	Power dissipation capacitance	f = 1 MHz No Load	12	pF

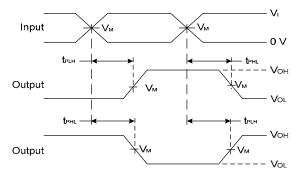
Parameter Measurement Information



V _{cc}	/cc Inputs V _M		CL	
•00	VI	t _r /t _f	• M	υĽ
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	15pF
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	15pF
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	50pF
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	50pF







Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$



Ordering Information

74AHC1G04

SINGLE INVERTER GATE

Packing

7: Tape & Reel

Logic Device 74 : Logic Prefix AHC : 2 to 5.5V Family 1G : One gate Device Packa Code 74AHC1G04W5-7 W5 74AHC1G04SE-7 SE Notes: 5. Pad layout as shown on Diodes Inter/Www.diodes.com/datasheets

EW PRODUCT

Ζ

1G : One	,			
Davias	Package	Packaging	7" Tape	and Reel
Device	Code	(Note 5)	Quantity	Part Number Suffix
74AHC1G04W5-7	W5	SOT25	3000/Tape & Reel	-7
74AHC1G04SE-7	SE	SOT353	3000/Tape & Reel	-7

74AHC1G 04 XX - 7

Package

W5 : SOT25

SE : SOT353

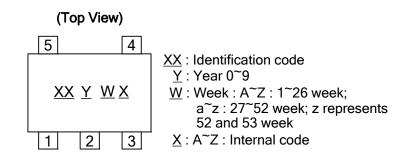
Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Function

Inverter - Gate

04:1-Input

Marking Information



Part Number	Package	Identification Code
74AHC1G04W5	SOT25	ΥT
74AHC1G04SE	SOT353	ΥT

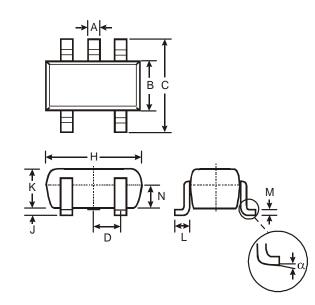


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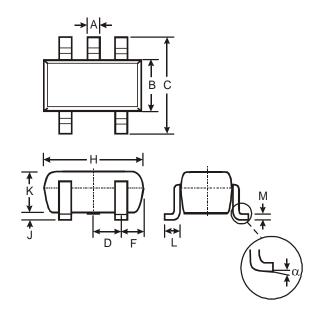
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



	SO	25	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D		_	0.95
Н	2.90	3.10	3.00
J	0.013	0.10	0.05
Κ	1.00	1.30	1.10
L	0.35	0.55	0.40
Μ	0.10	0.20	0.15
Ν	0.70	0.80	0.75
α	0°	8°	
All D	imensi	ons in	mm

(2) Package Type: SOT353



SOT353		
Dim	Min	Max
Α	0.10	0.30
В	1.15	1.35
С	2.00	2.20
D	0.65 Тур	
F	0.40	0.45
Н	1.80	2.20
J	0	0.10
κ	0.90	1.00
L	0.25	0.40
Μ	0.10	0.22
α	0°	8°
All Dimensions in mm		



SINGLE INVERTER GATE



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